

SNOSAX3B - DECEMBER 2007 - REVISED JANUARY 2010

## LMP2015 Single/LMP2016 Dual High Precision, Rail-to-Rail Output Operational Amplifier

Check for Samples: LMP2015, LMP2016

## **FEATURES**

- (For V<sub>S</sub> = 5V, Typical Unless Otherwise Noted)
- Low Ensured V<sub>OS</sub> Over Temperature 10 μV
- Low Noise with no 1/f 35 nV/√Hz
- High CMRR 130 dB
- High PSRR 120 dB
- High A<sub>VOL</sub> 130 dB
- Wide Gain Bandwidth Product 3 MHz
- High Slew Rate 4 V/µs
- Low Supply Current 930 μA
- Rail-to-Rail Output 30 mV
- No External Capacitors Required

### **APPLICATIONS**

- Precision Instrumentation Amplifiers
- Thermocouple Amplifiers
- Strain Gauge Bridge Amplifier
- ADC Driver

## **DESCRIPTION**

The LMP2015/LMP2016 are the first members of TI's new LMP<sup>TM</sup> precision amplifier family. LMP2015/LMP2016 offer unprecedented accuracy and stability in space-saving miniature packaging at an affordable price. These devices utilize patented techniques to measure and continually correct the input offset error voltage. The result is a series of amplifiers which are ultra stable over time and temperature. They have excellent CMRR and PSRR ratings, and do not exhibit the familiar 1/f voltage and current noise increase that plagues traditional amplifiers. The combination of characteristics makes the LMP2015/LMP2016 good choices for transducer amplifiers, high gain configurations, ADC buffer amplifiers, DAC I-V conversion, or any other 2.7V-5V application requiring precision and long term stability.

Other useful benefits of the LMP2015/LMP2016 are rail-to-rail output, a low supply current of 930  $\mu$ A, and a wide gain bandwidth product of 3 MHz. These extremely versatile features provide high performance and ease of use.

## **Connection Diagram**

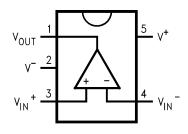


Figure 1. 5-Pin SOT-23 Top View

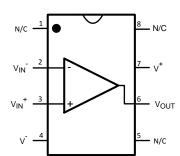


Figure 2. 8-Pin SOIC Top View

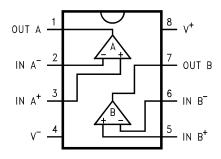
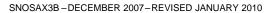


Figure 3. 8-Pin VSSOP Top View



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





## Absolute Maximum Ratings(1)(2)

ESD Tolerance <sup>(3)</sup>	Human Body Model	2000V
	Machine Model	200V
Supply Voltage	•	5.8V
Common Mode Input Voltage		-0.3 ≤ V <sub>CM</sub> ≤ V <sub>CC</sub> +0.3V
Lead Temperature (soldering 10	sec.)	+300°C
Differential Input Voltage		±Supply Voltage
Current at Input Pin		30 mA
Current at Output Pin		30 mA
Current at Power Supply Pin		50 mA

- (1) Absolute Maximum Ratings indicate limits beyond which damage may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and test conditions, see the Electrical Characteristics.
- (2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (3) Human Body Model, applicable std. MIL-STD-883, Method 3015.7. Machine Model, applicable std. JESD22-A115-A (ESD MM std. of JEDEC)Field-Induced Charge-Device Model, applicable std. JESD22-C101-C (ESD FICDM std. of JEDEC).

## Operating Ratings<sup>(1)</sup>

Supply Voltage	2.7V to 5.25V
Storage Temperature Range	−65°C to 150°C
Temperature Range <sup>(2)</sup>	-40°C to 125°C

- (1) Absolute Maximum Ratings indicate limits beyond which damage may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and test conditions, see the Electrical Characteristics.
- (2) The maximum power dissipation is a function of  $T_{J(MAX)}$ ,  $\theta_{JA}$ . The maximum allowable power dissipation at any ambient temperature is  $P_D = (T_{J(MAX)} T_A)/\theta_{JA}$ . All numbers apply for packages soldered directly onto a PC Board.

## 2.7V DC Electrical Characteristics

Unless otherwise specified, all limits ensured for  $T_A = 25^{\circ}C$ ,  $V^+ = 2.7V$ ,  $V^- = 0V$ ,  $V_{CM} = 1.35V$ ,  $V_O = 1.35V$  and  $R_L > 1$  M $\Omega$ . **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min <sup>(1)</sup>	Typ <sup>(2)</sup>	Max <sup>(1)</sup>	Units
$V_{OS}$	Input Offset Voltage (LMP2015 only)			0.8	5 <b>10</b>	\/
	Input Offset Voltage (LMP2016 only)			0.8	5 <b>10</b>	μV
	Offset Calibration Time			0.5	10 <b>12</b>	ms
TCV <sub>OS</sub>	Input Offset Voltage			0.015	.05	μV/°C
	Long Term Offset Drift			0.006		μV/month
	Lifetime V <sub>OS</sub> Drift			2.5		μV
I <sub>IN</sub>	Input Current			-3		рА
Ios	Input Offset Current			6		рА
R <sub>IND</sub>	Input Differential Resistance			9		ΜΩ
CMRR	Common Mode Rejection Ratio	$-0.3 \le V_{CM} \le 0.9V$ $0 \le V_{CM} \le 0.9V$	95 <b>90</b>	130		dB
CMVR	Input Common Mode Range	CMRR ≥ 95 dB	-0.3		0.9	V
		CMRR ≥ 90 dB	0		0.9	\ \ \
PSRR	Power Supply Rejection Ratio	$V^+ - V^- = 2.7V$ to 5V, $V_{CM} = 0V$	95 <b>90</b>	120		dB

<sup>(1)</sup> Limits are 100% production tested at 25°C. Limits over the operating temperature range are guaranteed through correlations using statistical quality control (SQC) method.

<sup>(2)</sup> Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not specified on shipped production material.

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## 2.7V DC Electrical Characteristics (continued)

Unless otherwise specified, all limits ensured for  $T_A = 25^{\circ}C$ ,  $V^+ = 2.7V$ ,  $V^- = 0V$ ,  $V_{CM} = 1.35V$ ,  $V_O = 1.35V$  and  $R_L > 1$  M $\Omega$ . **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min <sup>(1)</sup>	Typ <sup>(2)</sup>	Max <sup>(1)</sup>	Units
V <sub>O</sub>	Output Swing (LMP2015 only)	$R_L = 10 \text{ k}\Omega \text{ to } 1.35\text{V}$ $V_{IN}(\text{diff}) = \pm 0.5\text{V}$	2.665 <b>2.655</b>	2.68		V
				0.033	0.060 <b>0.075</b>	V
		$R_L = 2 k\Omega$ to 1.35V V <sub>IN</sub> (diff) = ±0.5V	2.630 <b>2.615</b>	2.65		V
				0.061	0.085 <b>0.105</b>	V
	Output Swing (LMP2016 only)	$R_L = 10 \text{ k}\Omega \text{ to } 1.35\text{V}$ $V_{IN}(\text{diff}) = \pm 0.5\text{V}$	2.64 <b>2.63</b>	2.68		V
				0.033	0.060 <b>0.075</b>	
		$R_L = 2 k\Omega$ to 1.35V $V_{IN}(diff) = \pm 0.5V$	2.615 <b>2.6</b>	2.65		V
				0.061	0.085 <b>0.105</b>	
A <sub>VOL</sub>	Open Loop Voltage Gain	$R_L = 10 \text{ k}\Omega$	95 <b>90</b>	130		dB
		$R_L = 2 k\Omega$	90 <b>85</b>	124		uБ
lo	Output Current	Sourcing, $V_O = 0V$ $V_{IN}(diff) = \pm 0.5V$	5 <b>3</b>	12		A
		Sinking, $V_O = 5V$ $V_{IN}(diff) = \pm 0.5V$	5 <b>3</b>	18		mA
I <sub>S</sub>	Supply Current per Channel			0.919	1.20 <b>1.50</b>	mA

### 2.7V AC Electrical Characteristics

 $T_A = 25^{\circ}\text{C}$ ,  $V^+ = 2.7\text{V}$ ,  $V^- = 0\text{V}$ ,  $V_{CM} = 1.35\text{V}$ ,  $V_O = 1.35\text{V}$ , and  $R_L > 1$  M $\Omega$ .**Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min <sup>(1)</sup>	Typ <sup>(2)</sup>	Max <sup>(1)</sup>	Units
GBWP	Gain Bandwidth Product			3		MHz
SR	Slew Rate			4		V/µs
θ <sub>m</sub>	Phase Margin			60		Deg
G <sub>m</sub>	Gain Margin			-14		dB
e <sub>n</sub>	Input Referred Voltage Noise			35		nV/√ <del>Hz</del>
i <sub>n</sub>	Input Referred Current Noise					pA/√Hz
e <sub>n</sub> p-p	Input Referred Voltage Noise	$R_S = 100\Omega$ , DC to 10 Hz		850		nV <sub>PP</sub>
t <sub>rec</sub>	Input Overload Recovery Time			50		ms

<sup>(1)</sup> Limits are 100% production tested at 25°C. Limits over the operating temperature range are guaranteed through correlations using statistical quality control (SQC) method.

<sup>(2)</sup> Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not specified on shipped production material.



## **5V DC Electrical Characteristics**

Unless otherwise specified, all limits ensured for  $T_A = 25^{\circ}C$ ,  $V^+ = 5V$ ,  $V^- = 0V$ ,  $V_{CM} = 2.5V$ ,  $V_O = 2.5V$  and  $R_L > 1$  M $\Omega$ . **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min <sup>(1)</sup>	Typ <sup>(2)</sup>	Max <sup>(1)</sup>	Units
V <sub>OS</sub>	Input Offset Voltage (LMP2015 only)			0.12	5 <b>10</b>	μV
	Input Offset Voltage (LMP2016 only)			0.12	5 <b>10</b>	μν
	Offset Calibration Time			0.5	10 <b>12</b>	ms
$TCV_OS$	Input Offset Voltage			0.015	.05	μV/°C
	Long Term Offset Drift			0.006		μV/month
	Lifetime V <sub>OS</sub> Drift			2.5		μV
I <sub>IN</sub>	Input Current			-3		pA
I <sub>OS</sub>	Input Offset Current			6		pA
R <sub>IND</sub>	Input Differential Resistance			9		ΜΩ
CMRR	Common Mode Rejection Ratio	$-0.3 \le V_{CM} \le 3.2$ $0 \le V_{CM} \le 3.2$	100 <b>90</b>	130		dB
CMVR	Input Common Mode Range	CMRR ≥ 100 dB	-0.3		3.2	\/
		CMRR ≥ 90 dB	0		3.2	V
PSRR	Power Supply Rejection Ratio	$V^+ - V^- = 2.7V$ to 5V, $V_{CM} = 0V$	95 <b>90</b>	120		dB
Vo	Output Swing (LMP2015 only)	$R_L = 10 \text{ k}\Omega \text{ to } 2.5\text{V}$ $V_{IN}(\text{diff}) = \pm 0.5\text{V}$	4.96 <b>4.95</b>	4.978		V
				0.040	0.070 <b>0.085</b>	
		$R_L = 2 \text{ k}\Omega \text{ to } 2.5\text{V}$ $V_{IN}(\text{diff}) = \pm 0.5\text{V}$	4.895 <b>4.875</b>	4.919		V
				0.091	0.115 <b>0.140</b>	
	Output Swing (LMP2016 only)	$R_L = 10 \text{ k}\Omega \text{ to } 2.5\text{V}$ $V_{IN}(\text{diff}) = \pm 0.5\text{V}$	4.92 <b>4.91</b>	4.978		V
				0.040	0.080 <b>0.095</b>	V
		$R_L = 2 \text{ k}\Omega \text{ to } 2.5\text{V}$ $V_{IN}(\text{diff}) = \pm 0.5\text{V}$	4.875 <b>4.855</b>	4.919		V
				0.091	0.125 <b>0.150</b>	·
$A_{VOL}$	Open Loop Voltage Gain	R <sub>L</sub> = 10 kΩ	105 <b>100</b>	130		dB
		$R_L = 2 k\Omega$	95 <b>90</b>	132		uБ
Io	Output Current	Sourcing, $V_O = 0V$ $V_{IN}(diff) = \pm 0.5V$	8 <b>6</b>	15		mA
		Sinking, $V_O = 5V$ $V_{IN}(diff) = \pm 0.5V$	8 <b>6</b>	17		IIIA
I <sub>S</sub>	Supply Current per Channel			0.930	1.20 <b>1.50</b>	mA

<sup>(1)</sup> Limits are 100% production tested at 25°C. Limits over the operating temperature range are guaranteed through correlations using statistical quality control (SQC) method.

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## **5V AC Electrical Characteristics**

 $T_A = 25$ °C,  $V^+ = 5V$ ,  $V^- = 0V$ ,  $V_{CM} = 2.5V$ ,  $V_O = 2.5V$ , and  $R_L > 1$  M $\Omega$ . **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min <sup>(1)</sup>	Typ <sup>(2)</sup>	Max <sup>(1)</sup>	Units
GBW	Gain-Bandwidth Product			3		MHz
SR	Slew Rate			4		V/µs
θ <sub>m</sub>	Phase Margin			60		deg
G <sub>m</sub>	Gain Margin			-15		dB
e <sub>n</sub>	Input-Referred Voltage Noise			35		nV/√ <del>Hz</del>
in	Input-Referred Current Noise					pA/√ <del>Hz</del>
e <sub>n</sub> p-p	Input-Referred Voltage Noise	$R_S = 100\Omega$ , DC to 10 Hz		850		$nV_{PP}$
t <sub>rec</sub>	Input Overload Recovery Time			50		ms

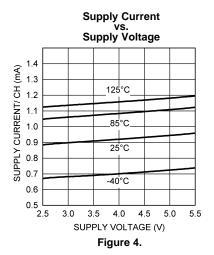
<sup>(1)</sup> Limits are 100% production tested at 25°C. Limits over the operating temperature range are guaranteed through correlations using statistical quality control (SQC) method.

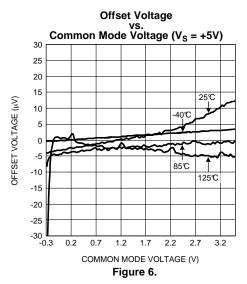
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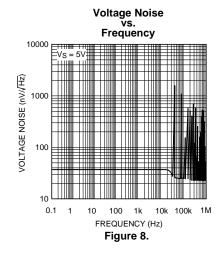


## **Typical Performance Characteristics**

 $T_A = 25$ °C,  $V_S = 5V$  unless otherwise specified.







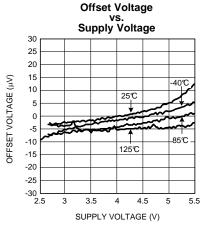


Figure 5.

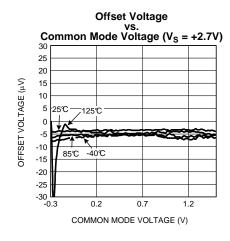
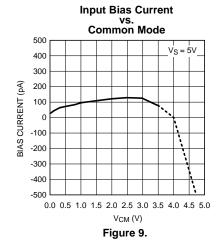


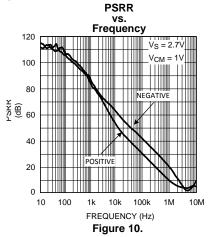
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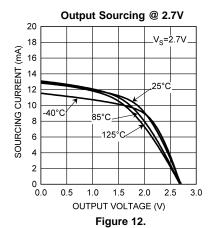


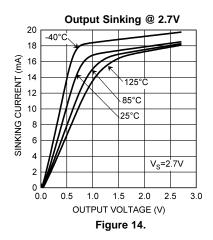
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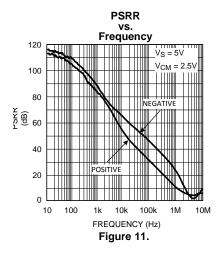
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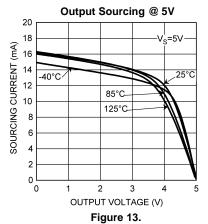
**INSTRUMENTS** 

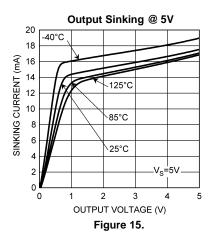








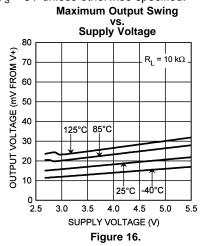


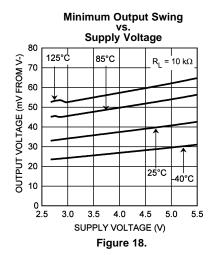


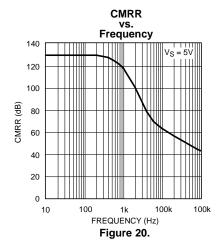


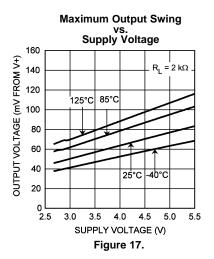
## **Typical Performance Characteristics (continued)**

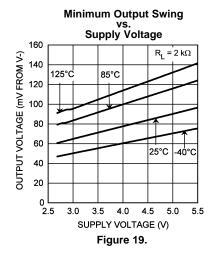
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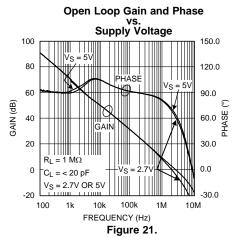








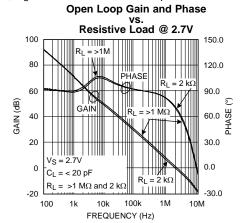




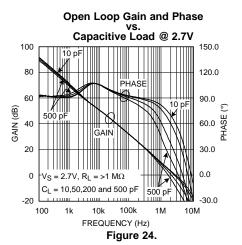
## **Typical Performance Characteristics (continued)**

 $T_A = 25$ °C,  $V_S = 5V$  unless otherwise specified.

**NSTRUMENTS** 



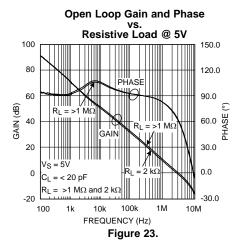


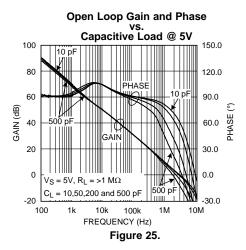


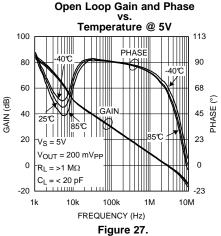
Temperature @ 2.7V 100 80 40 20  $V_{OUT} = 200 \text{ mV}_{PP}$  $R_L = >1 M\Omega$  $C_L = < 20 \text{ pF}$ -20 -23 100k

FREQUENCY (Hz) Figure 26.

Open Loop Gain and Phase





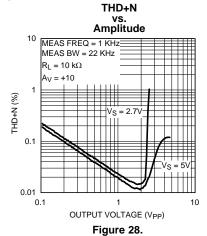


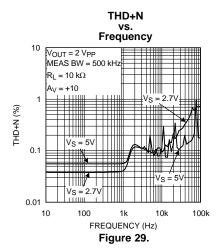
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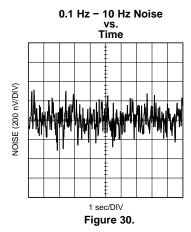


## **Typical Performance Characteristics (continued)**

 $T_A = 25$ °C,  $V_S = 5V$  unless otherwise specified.









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#### **APPLICATION INFORMATION**

# THE BENEFITS OF THE LMP2015/LMP2016'S NO 1/f NOISE

Using patented methods, the LMP2015/LMP2016 eliminate the 1/f noise present in other amplifiers. That noise, which increases as frequency decreases, is a major source of measurement error in all DC-coupled measurements. Low frequency noise appears as a constantly changing signal in series with any measurement being made. As a result, even when the measurement is made rapidly, this constantly changing noise signal will corrupt the result. The value of this noise signal can be surprisingly large. For example: If a conventional amplifier has a flat-band noise level of 10 nV/ $\sqrt{\text{Hz}}$  and a noise corner of 10 Hz, the RMS noise at 0.001 Hz is 1  $\mu\text{V}/\sqrt{\text{Hz}}$ . This is equivalent to a 0.50  $\mu\text{V}$  peak-to-peak error, in the frequency range 0.001 Hz to 1.0 Hz. In a circuit with a gain of 1000, this produces a 0.50 mV peak-to-peak output error. This number of 0.001 Hz might appear unreasonably low, but when a data acquisition system is operating for 17 minutes, it has been on long enough to include this error. In this same time, the LMP2015/LMP2016 will have only a 0.21 mV output error. This is smaller by 2.4 x. Keep in mind that this 1/f error gets even larger at lower frequencies. At the extreme, many people try to reduce this error by integrating or taking several samples of the same signal. This is also doomed to failure because the 1/f nature of this noise means that taking longer samples just moves the measurement into lower frequencies where the noise level is even higher.

The LMP2015/LMP2016 eliminate this source of error. The noise level is constant with frequency so that reducing the bandwidth reduces the errors caused by noise.

Another source of error that is rarely mentioned is the error voltage caused by the inadvertent thermocouples created when the common "Kovar type" IC package lead materials are soldered to a copper printed circuit board. These steel based leadframe materials can produce over 35  $\mu$ V/°C when soldered onto a copper trace. This can result in thermocouple noise that is equal to the LMP2015/LMP2016 noise when there is a temperature difference of only 0.0014°C between the lead and the board!

For this reason, the lead frame of the LMP2015/LMP2016 is made of copper. This results in equal and opposite junctions which cancel this effect. The extremely small size of the SOT23 package results in the leads being very close together. This further reduces the probability of temperature differences and hence decreases thermal noise.

## **OVERLOAD RECOVERY**

The LMP2015/LMP2016 recover from input overload much faster than most chopper-stabilized op amps. Recovery from driving the amplifier to 2X the full scale output, only requires about 40 ms. Many chopper-stabilized amplifiers will take from 250 ms to several seconds to recover from this same overload. This is because large capacitors are used to store the unadjusted offset voltage.

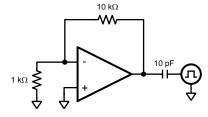


Figure 31. Overload Recovery Test

The wide bandwidth of the LMP2015/LMP2016 enhance performance when it is used as an amplifier to drive loads that inject transients back into the output. ADCs (Analog-to-Digital Converters) and multiplexers are examples of this type of load. To simulate this type of load, a pulse generator producing a 1V peak square wave was connected to the output through a 10 pF capacitor. (Figure 31) The typical time for the output to recover to 1% of the applied pulse is 80 ns. To recover to 0.1% requires 860 ns. This rapid recovery is due to the wide bandwidth of the output stage and large total GBWP.



#### NO EXTERNAL CAPACITORS REQUIRED

The LMP2015/LMP2016 do not need external capacitors. This eliminates the problems caused by capacitor leakage and dielectric absorption, which can cause delays of several seconds from turn-on until the amplifier's error has settled.

#### **MORE BENEFITS**

The LMP2015/LMP2016 offer the benefits mentioned above and more. These parts have rail-to-rail outputs and consume only 950  $\mu$ A of supply current while providing excellent DC and AC electrical performance. In DC performance, the LMP2015/LMP2016 achieve 130 dB of CMRR, 120 dB of PSRR and 130 dB of open loop gain. In AC performance, the LMP2015/LMP2016 provide 3 MHz of gain bandwidth product and 4 V/ $\mu$ s of slew rate.

#### **HOW THE LMP2015/LMP2016 WORK**

The LMP2015/LMP2016 use new, patented techniques to achieve the high DC accuracy traditionally associated with chopper-stabilized amplifiers without the major drawbacks produced by chopping. The LMP2015/LMP2016 continuously monitor the input offset and correct this error. The conventional chopping process produces many mixing products, both sums and differences, between the chopping frequency and the incoming signal frequency. This mixing causes a large amount of distortion, particularly when the signal frequency approaches the chopping frequency. Even without an incoming signal, the chopper harmonics mix with each other to produce even more trash. To explain this Figure 32 shows a plot, of the output of a typical (MAX432) chopper-stabilized op amp. This is the output when there is no incoming signal, just the amplifier in a gain of −10 with the input grounded. The chopper is operating at about 150 Hz; the rest is mixing products. Add an input signal and the noise gets much worse. Compare this plot with Figure 33 of the LMP2015/LMP2016. This data was taken under the exact same conditions. The auto-zero action is visible at about 30 kHz but note the absence of mixing products at other frequencies. As a result, the LMP2015/LMP2016 have very low distortion of 0.02% and very low mixing products.

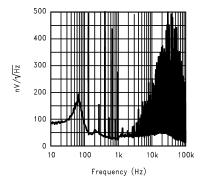


Figure 32. The Output of a Chopper Stabilized Op Amp (MAX432)

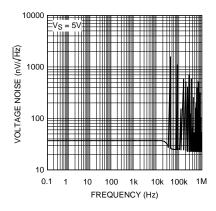


Figure 33. The Output of the LMP2015/LMP2016

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#### **INPUT CURRENTS**

The LMP2015/LMP2016 input currents are different than standard bipolar or CMOS input currents in that it appears as a current flowing in one input and out the other. Under most operating conditions, these currents are in the picoamp level and will have little or no effect in most circuits. These currents tend to increase slightly when the common-mode voltage is near the minus supply (See the Typical Performance Characteristics). At high temperatures such as 85°C, the input currents become larger, 0.5 nA typical, and are both positive except when the  $V_{CM}$  is near  $V^-$ . If operation is expected at low common-mode voltages and high temperature, do not add resistance in series with the inputs to balance the impedances. Doing this can cause an increase in offset voltage. A small resistance such as 1 k $\Omega$  can provide some protection against very large transients or overloads, and will not increase the offset significantly.

## PRECISION STRAIN GAUGE AMPLIFIER

This strain gauge amplifier (Figure 34) provides high gain (1006 or ~60 dB) with very low offset and drift. Using the resistors' tolerances as shown, the worst case CMRR will be greater than 108 dB. The CMRR is directly related to the resistor mismatch. The rejection of common-mode error, at the output, is independent of the differential gain, which is set by R3. The CMRR is further improved, if the resistor ratio matching is improved, by specifying tighter-tolerance resistors, or by trimming.

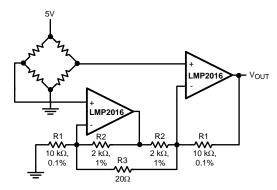


Figure 34. Precision Strain Gauge Amplifier

#### Extending Supply Voltages and Output Swing by Using a Composite Amplifier Configuration

In cases where substantially higher output swing is required with higher supply voltages, arrangements such as those shown in Figure 35 and Figure 36 can be used. These configurations utilize the excellent DC performance of the LMP2015 while allowing the superior voltage and frequency capabilities of the LM6171 to set the dynamic performance of the overall amplifier. For example, it is possible to achieve  $\pm 12V$  output swing with 300 MHz of overall GBW ( $A_V = 100$ ) while keeping the worst case output shift due to  $V_{OS}$  less than 4 mV. The LMP2015 output voltage is kept at about mid-point of its overall supply voltage, and its input common mode voltage range allows the  $V^-$  terminal to be grounded in one case (Figure 35, inverting operation) and tied to a small non-critical negative bias in another (Figure 36, non-inverting operation). Higher closed loop gains are also possible with a corresponding reduction in realizable bandwidth. Table 1 shows some other closed loop gain possibilities along with the measured performance in each case.



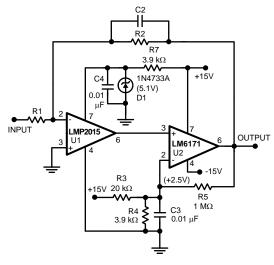


Figure 35. Composite Amplifier Configuration

**Table 1. Composite Amplifier Measured Performance** 

AV	R1 Ω	R2 Ω	C2 pF	BW MHz	SR (V/µs)	en p-p (mV <sub>PP</sub> )
50	200	10k	8	3.3	178	37
100	100	10k	10	2.5	174	70
100	1k	100k	0.67	3.1	170	70
500	200	100k	1.75	1.4	96	250
1000	100	100k	2.2	0.98	64	400

In terms of the measured output peak-to-peak noise, the following relationship holds between output noise voltage;  $e_n$  p-p, the closed-loop gain;  $A_V$ , and -3 dB bandwidth; BW:

$$\frac{e_{npp1}}{e_{npp2}} = \sqrt{\frac{BW1}{BW2}} \bullet \frac{A_V 1}{A_V 2}$$
 (1)

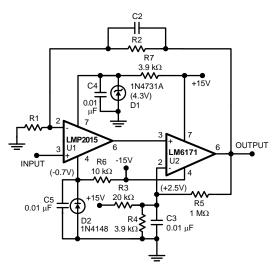


Figure 36. Composite Amplifier Configuration

It should be kept in mind that in order to minimize the output noise voltage for a given closed loop gain setting, one could minimize the overall bandwidth. As can be seen from Equation 1, the output noise has a square root relationship to the bandwidth.

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In the case of the inverting configuration, it is also possible to increase the input impedance of the overall amplifier by raising the value of R1. This can be done without having to increase the feedback resistor, R2, to impractical values, by utilizing a "Tee" network as feedback. See the LMC6442 datasheet (Application Information section) for more details on this.

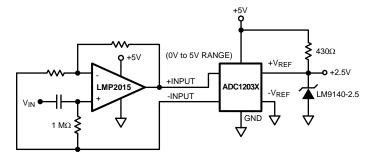


Figure 37. AC Coupled ADC Driver

## LMP2015 AS AN ADC DRIVER

The LMP2015 is a great choice for an amplifier stage immediately before the input of an ADC (Analog-to-Digital Converter) as an ADC driver, whether AC or DC coupled. See Figure 37 and Figure 38. This is because of the following important characteristics:

- A) Very low offset voltage and offset voltage drift over time and temperature allow a high closed loop gain setting without introducing any short term or long term errors. For example, when set to a closed loop gain of 100 as the analog input amplifier for a 12-bit A/D converter, the overall conversion error over full operation temperature and 30 year life of the part (operating at 50°C) would be less than 5 LSBs.
- **B)** Fast large signal settling time to 0.01% of final value(1.4 μs) allows 12-bit accuracy at a sampling rate of 100 kHz or more.
- C) No flicker (1/f) noise means unsurpassed data accuracy over any measurement period of time, no matter how long. Consider the following op amp performance, based on a typical low noise, high performance commercially-available device, for comparison:

Op amp flatband noise = 8 nV/√Hz
1/f corner frequency = 100 Hz
A<sub>V</sub> = 2000
Measurement time = 100 sec
Bandwidth = 2 Hz

This example will result in about 2.2 mV<sub>PP</sub> (1.9 LSB) of output noise contribution due to the op amp alone, compared to about 594  $\mu$ V<sub>PP</sub> (less than 0.5 LSB) when that op amp is replaced with the LMP2015 which has no 1/f contribution. If the measurement time is increased from 100 seconds to 1 hour, the improvement realized by using the LMP2015 would be a factor of about 4.8 times (2.86 mV<sub>PP</sub> compared to 596  $\mu$ V when LMP2015 is used). This is mainly because the LMP2015 accuracy is not compromised by increasing the observation time.

- D) Copper leadframe construction minimizes any thermocouple effects which would degrade low level/high gain data conversion application accuracy (see discussion in THE BENEFITS OF THE LMP2015/LMP2016's NO 1/f NOISE section).
- **E)** Rail-to-Rail output swing maximizes the ADC dynamic range in 5V single supply converter applications. Figure 37 and Figure 38 are typical block diagrams showing the LMP2015 used as an ADC driver.

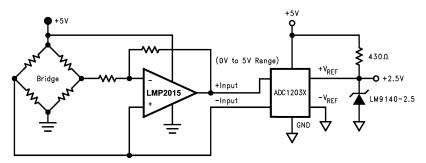


Figure 38. DC Coupled ADC Driver

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